

Low Charge Injection 8-Channel Enhanced High Voltage Analog Switch

Features

- ▶ HVCMOS technology for high performance
- ▶ 8 Channels of high voltage analog switch
- ▶ 3.3V or 5V CMOS input logic level
- ▶ 20MHz data shift clock frequency
- ▶ Very low quiescent power dissipation-10 μ A
- ▶ Low parasitic capacitance
- ▶ DC to 10MHz analog signal frequency
- ▶ -60dB typical off-isolation at 5MHz
- ▶ CMOS logic circuitry for low power
- ▶ Excellent noise immunity
- ▶ Cascadable serial data register with latches
- ▶ Flexible operating supply voltages

Applications

- ▶ Medical ultrasound imaging
- ▶ NDT metal flaw detection
- ▶ Piezoelectric transducer drivers
- ▶ Inkjet printer heads
- ▶ Optical MEMS modules

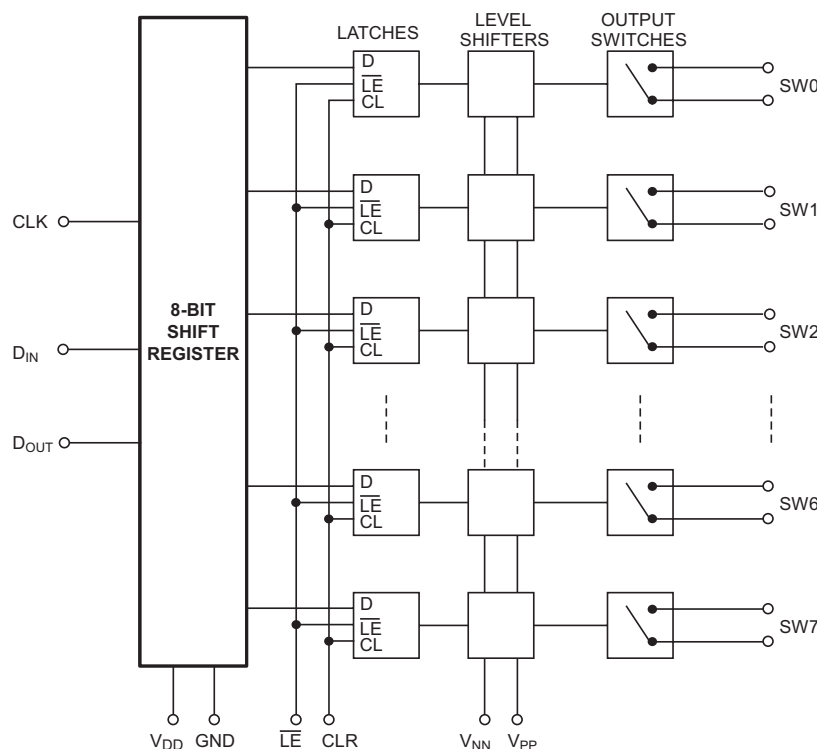
General Description

The Supertex HV2201 is a low charge injection, 8-channel, high voltage analog switch integrated circuit (IC). The device can be used in applications requiring high voltage switching controlled by low voltage control signals, such as medical ultrasound imaging, piezoelectric transducer drivers, and printers. The HV2201 is an enhanced version of the HV20220.

Input data is shifted into an 8-bit shift register that can then be retained in an 8-bit latch. To reduce any possible clock feed-through noise, the latch enable bar should be left high until all bits are clocked in. Data is clocked in during the rising edge of the clock. Using HVCMOS technology, this device combines high voltage bilateral DMOS switches and low power CMOS logic to provide efficient control of high voltage analog signals.

The device is suitable for various combinations of high voltage supplies, e.g., V_{PP}/V_{NN} : +40V/-160V, +100V/-100V, and +160V/-40V.

Block Diagram



NR032106

Ordering Information

Device	Package Options		
	48-Lead TQFP	28-Lead PLCC	32-Lead BCC
HV2201	HV2201FG-G	HV2201PJ-G	HV2201B1-G

-G indicates package is RoHS compliant ("Green")



Absolute Maximum Ratings

Parameter	Value
V_{DD} logic supply	-0.5V to +7V
V_{PP} - V_{NN} differential supply	220V
V_{PP} positive supply	-0.5V to V_{NN} +200V
V_{NN} negative supply	+0.5V to -200V
Logic input voltage	-0.5V to V_{DD} +0.3V
Analog signal range	V_{NN} to V_{PP}
Peak analog signal current/channel	3.0A
Storage temperature	-65°C to 150°C
Power dissipation:	
48-Lead TQFP	1.0W
28-Lead PLCC	1.2W
32-Lead BCC	1.0W

Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these conditions is not implied. Continuous operation of the device at the absolute rating level may affect device reliability. All voltages are referenced to device ground.

Operating Conditions

Symbol	Parameter	Value
V_{DD}	Logic power supply voltage	3.0V to 5.5V
V_{PP}	positive high voltage supply	40V to V_{NN} +200V
V_{NN}	negative high voltage supply	-40V to -160V
V_{IH}	High level input voltage	0.9V to V_{DD}
V_{IL}	Low-level input voltage	0V to 0.1V
V_{SIG}	Analog signal voltage peak-to-peak	V_{NN} +10V to V_{PP} -10V
T_A	Operating free air temperature	0°C to 70°C

Notes:

1. Power up/down sequence is arbitrary except GND must be powered -up first and powered down last.
2. V_{SIG} must be $V_{NN} \leq V_{SIG} \leq V_{PP}$ or floating during power up/down transition.
3. Rise and fall times of power supplies V_{DD} , V_{PP} and V_{NN} should not be less than 1.0msec.

DC Electrical Characteristics

(Over operating conditions unless otherwise specified)

Sym	Parameter	0°C		+25°C			+70°C		Units	Conditions		
		Min	Max	Min	Typ	Max	Min	Max				
R _{ONS}	Small signal switch on-resistance	-	30	-	26	38	-	48	Ω	I _{SIG} = 5mA	V _{PP} = +40V	
		-	25	-	22	27	-	32		I _{SIG} = 200mA	V _{NN} = -160V	
		-	25	-	22	27	-	30		I _{SIG} = 5mA	V _{PP} = +100V	
		-	18	-	18	24	-	27		I _{SIG} = 200mA	V _{NN} = -100V	
		-	23	-	20	25	-	30		I _{SIG} = 5mA	V _{PP} = +160V	
		-	22	-	16	25	-	27		I _{SIG} = 200mA	V _{NN} = -40V	
ΔR _{ONS}	Small signal switch on-resistance matching	-	20	-	5.0	20	-	20	%	I _{SIG} = 5mA, V _{PP} = +100V, V _{NN} = -100V		
R _{ONL}	Large signal switch on-resistance	-	-	-	15	-	-	-	Ω	V _{SIG} = V _{PP} -10V, I _{SIG} = 1A		
I _{SOL}	Switch off leakage per switch	-	5.0	-	1.0	10	-	15	μA	V _{SIG} = V _{PP} -10V, V _{NN} +10V		
V _{OS}	DC offset switch off	-	300	-	100	300	-	300	mV	100kΩ load		
	DC offset switch on	-	500	-	100	500	-	500	mV			
I _{PPQ}	Quiescent V _{PP} supply current	-	-	-	10	50	-	-	μA	All switches off		
I _{NNQ}	Quiescent V _{NN} supply current	-	-	-	-10	-50	-	-	μA	All switches off		
I _{PPQ}	Quiescent V _{PP} supply current	-	-	-	10	50	-	-	μA	All switches on, I _{SW} = 5mA		
I _{NNQ}	Quiescent V _{NN} supply current	-	-	-	-10	-50	-	-	μA	All switches on, I _{SW} = 5mA		
I _{SW}	Switch output peak current	-	3.0	-	3.0	2.0	-	2.0	A	V _{SIG} duty cyclcy < 0.1%		
f _{SW}	Output switching frequency	-	-	-	-	50	-	-	kHz	Duty cycle = 50%		
I _{PP}	Average V _{PP} supply current	-	4.0	-	-	5.0	-	5.5	mA	V _{PP} = +40V V _{NN} = -160V	All output switches are turning On and Off at 50kHz with no load	
		-	3.5	-	-	3.5	-	3.5		V _{PP} = +100V V _{NN} = -100V		
		-	3.5	-	-	3.5	-	4.0		V _{PP} = +160V V _{NN} = -40V		
I _{NN}	Average V _{NN} supply curent	-	4.5	-	-	5.0	-	5.5	mA	V _{PP} = +40V V _{NN} = -160V		
		-	3.5	-	-	3.5	-	3.5		V _{PP} = +100V V _{NN} = -100V		
		-	3.5	-	-	3.5	-	4.0		V _{PP} = +160V V _{NN} = -40V		
I _{DD}	Average V _{DD} supply current	-	4.0	-	-	4.0	-	4.0	mA	f _{CLK} = 5MHz, V _{DD} = 5.0V		
I _{DDQ}	Quiescent V _{DD} supply current	-	10	-	-	10	-	10	μA	All logic inputs are static		
I _{SOR}	Data out source current	0.45	-	0.45	0.70	-	0.40	-	mA	V _{OUT} = V _{DD} -0.7V		
I _{SINK}	Data out sink current	0.45	-	0.45	0.70	-	0.40	-	mA	V _{OUT} = 0.7V		
C _{IN}	Logic input capacitance	-	10	-	-	10	-	10	pF	---		

AC Electrical Characteristics

(Over recommended operating conditions: $V_{DD} = 5.0V$, $t_R = t_F \leq 5ns$, 50% duty cycle, $C_{LOAD} = 20pF$, unless otherwise specified)

Sym	Parameter	0°C		+25°C			+70°C		Units	Conditions
		Min	Max	Min	Typ	Max	Min	Max		
t_{SD}	Set up time before $\overline{LE}$ rises	25	-	25	-	-	25	-	ns	---
t_{WLE}	Time width of $\overline{LE}$	56	-	-	56	-	56	-	ns	$V_{DD} = 3.0V$
		12	-	-	12	-	12	-		$V_{DD} = 5.0V$
t_{DO}	Clock delay time to data out	-	120	-	95	140	-	167	ns	$V_{DD} = 3.0V$
		-	58	-	40	69	-	85		$V_{DD} = 5.0V$
t_{WCL}	Time width of CL	55	-	55	-	-	55	-	ns	---
t_{SU}	Set up time data to clock	39	-	47	30	-	58	-	ns	$V_{DD} = 3.0V$
		16	-	21	10	-	26	-		$V_{DD} = 5.0V$
t_H	Hold time data from clock	2	-	2	-	-	2	-	ns	$V_{DD} = 3.0$ or $5.0V$
f_{CLK}	Clock frequency	-	-	-	8	-	-	-	MHz	$V_{DD} = 3.0V$
		-	-	-	20	-	-	-		$V_{DD} = 5.0V$
t_R, t_F	Clock rise and fall times	-	50	-	-	50	-	50	ns	---
t_{ON}	Turn on time	-	5.0	-	-	5.0	-	5.0	μs	$V_{SIG} = V_{PP} - 10V$, $R_{LOAD} = 10k\Omega$
t_{OFF}	Turn off time	-	5.0	-	-	5.0	-	5.0	μs	$V_{SIG} = V_{PP} - 10V$, $R_{LOAD} = 10k\Omega$
dv/dt	Maximum V_{SIG} slew rate	-	20	-	-	20	-	20	V/ns	$V_{PP} = +40V$, $V_{NN} = -160V$
		-	20	-	-	20	-	20		$V_{PP} = +100V$, $V_{NN} = -100V$
		-	20	-	-	20	-	20		$V_{PP} = +160V$, $V_{NN} = -40V$
K_O	Off isolation	-30	-	-30	-33	-	-30	-	dB	$f = 5.0MHz$, $1k\Omega/15pF$ load
		-58	-	-58	-	-	-58	-		$f = 5.0MHz$, 50Ω load
K_{CR}	Switch crosstalk	-60	-	-60	-70	-	-60	-	dB	$f = 5.0MHz$, 50Ω load
I_{ID}	Output switch isolation diode current	-	300	-	-	300	-	300	mA	300ns pulse width, 2.0% duty cycle
$C_{SG(OFF)}$	Off capacitance SW to GND	5.0	17	5.0	12	17	5.0	17	pF	0V, $f = 1.0MHz$
$C_{SG(ON)}$	On capacitance SW to GND	25	50	25	38	50	25	50	pF	0V, $f = 1.0MHz$
$+V_{SPK}$	Output voltage spike	-	-	-	-	150	-	-	mV	$V_{PP} = +40V$, $V_{NN} = -160V$, $R_{LOAD} = 50\Omega$
$-V_{SPK}$		-	-	-	-	150	-	-		
$+V_{SPK}$		-	-	-	-	150	-	-		$V_{PP} = +100V$, $V_{NN} = -100V$, $R_{LOAD} = 50\Omega$
$-V_{SPK}$		-	-	-	-	150	-	-		
$+V_{SPK}$		-	-	-	-	150	-	-		$V_{PP} = +160V$, $V_{NN} = -40V$, $R_{LOAD} = 50\Omega$
$-V_{SPK}$		-	-	-	-	150	-	-		
QC	Charge injection	-	-	-	820	-	-	-	pC	$V_{PP} = +40V$, $V_{NN} = -160V$, $V_{SIG} = 0V$
		-	-	-	600	-	-	-		$V_{PP} = +100V$, $V_{NN} = -100V$, $V_{SIG} = 0V$
		-	-	-	350	-	-	-		$V_{PP} = +160V$, $V_{NN} = -40V$, $V_{SIG} = 0V$

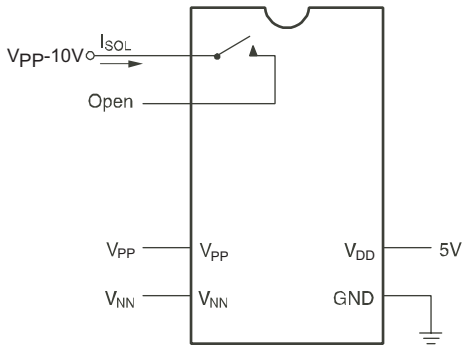
Truth Table

D0	D1	D2	D3	D4	D5	D6	D7	LE	CLR	SW0	SW1	SW2	SW3	SW4	SW5	SW6	SW7
L								L	L	Off							
H								L	L	On							
	L							L	L		Off						
	H							L	L		On						
		L						L	L			Off					
		H						L	L			On					
			L					L	L				Off				
			H					L	L				On				
				L				L	L					Off			
				H				L	L					On			
					L			L	L						Off		
					H			L	L						On		
						L		L	L							Off	
						H		L	L							On	
							L	L	L								Off
							H	L	L								On
X	X	X	X	X	X	X	X	H	L	Hold Previous State							
X	X	X	X	X	X	X	X	X	H	All Switches Off							

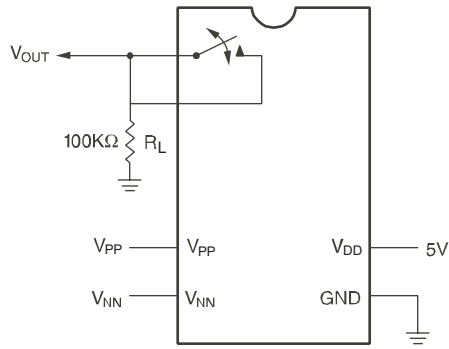
Notes:

1. The eight switches operate independently.
2. Serial data is clocked in on the L to H transition of the CLK.
3. The switches go to a state retaining their present condition at the rising edge of LE. When LE is low the shift register data flow through the latch.
4. D_{OUT} is high when data in the register 7 is high.
5. Shift register clocking has no effect on the switch states if LE is high.
6. The CLR clear input overrides all other inputs.

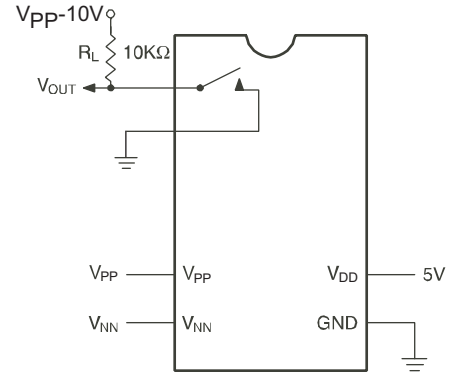
Test Circuits



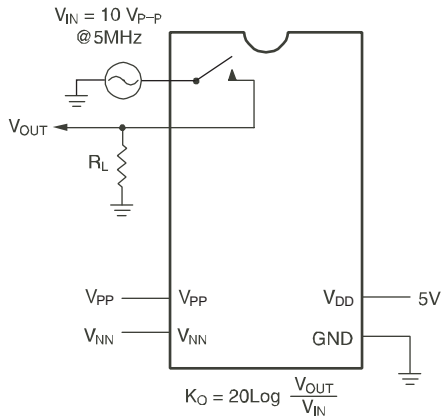
Switch OFF Leakage



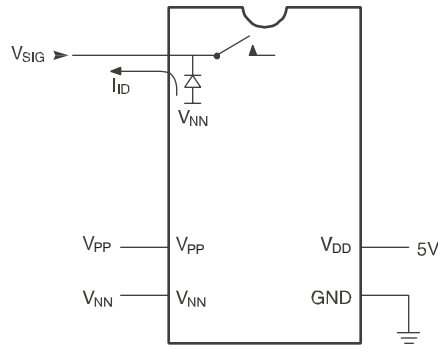
DC Offset ON/OFF



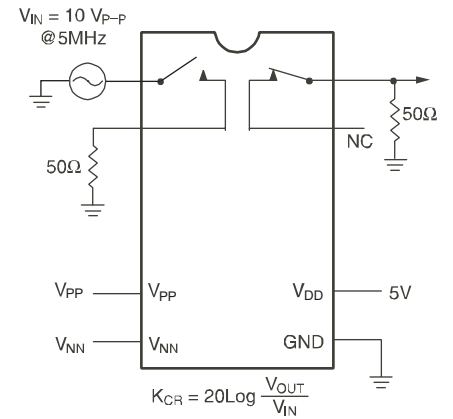
T_{ON}/T_{OFF} Test Circuit



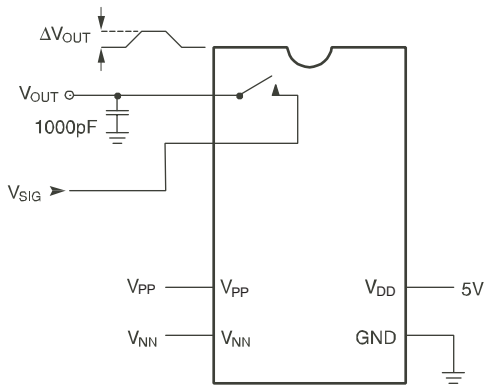
OFF Isolation



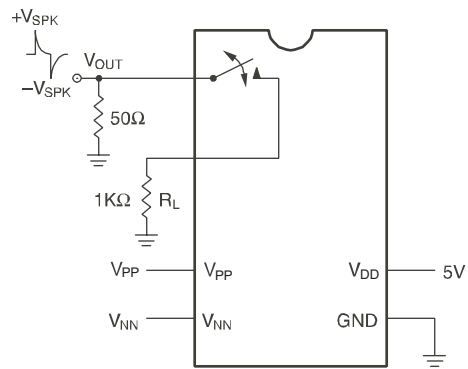
Isolation Diode Current



Crosstalk

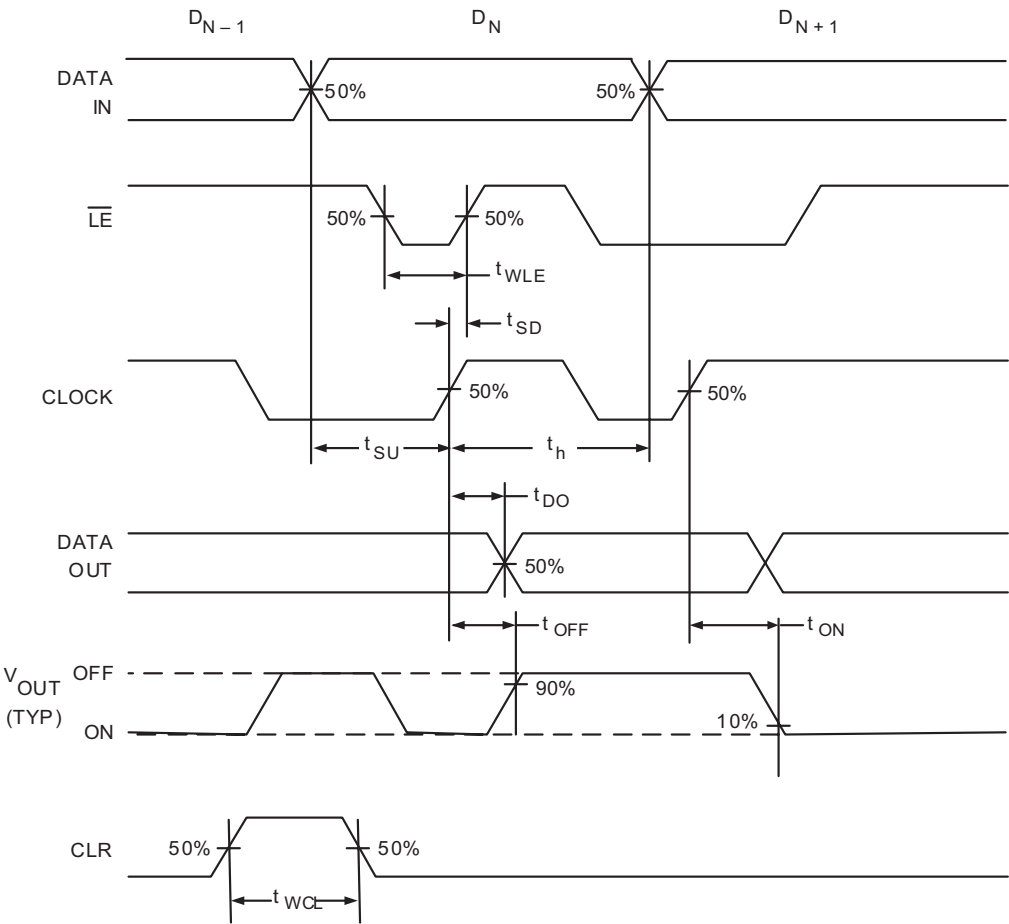


$Q = 1000pF \times \Delta V_{OUT}$
Charge Injection

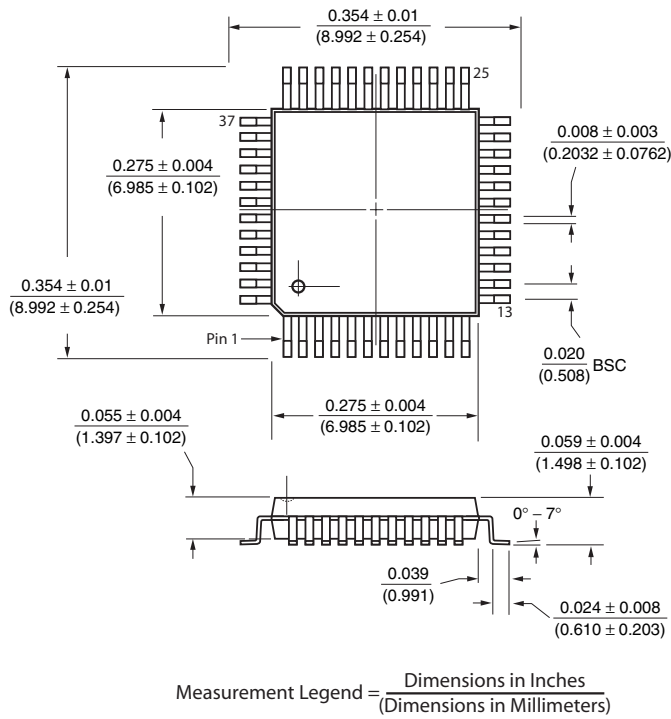


Output Voltage Spike

Typical Waveforms



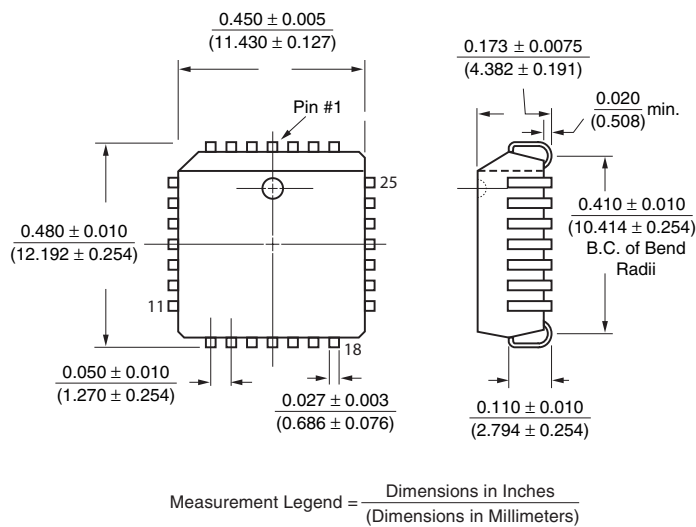
48-Lead TQFP (1.4mm) Package Outline (FG)



Pin Configuration

Pin #	Pin Name	Pin #	Pin Name
1	SW5	25	V_{NN}
2	NC	26	NC
3	SW4	27	NC
4	NC	28	GND
5	SW4	29	V_{DD}
6	NC	30	NC
7	NC	31	NC
8	SW3	32	NC
9	NC	33	D_{IN}
10	SW3	34	CLK
11	NC	35	$\overline{LE}$
12	SW2	36	CLR
13	NC	37	D_{OUT}
14	SW2	38	NC
15	NC	39	SW7
16	SW1	40	NC
17	NC	41	SW7
18	SW1	42	NC
19	NC	43	SW6
20	SW0	44	NC
21	NC	45	SW6
22	SW0	46	NC
23	NC	47	SW5
24	V_{PP}	48	NC

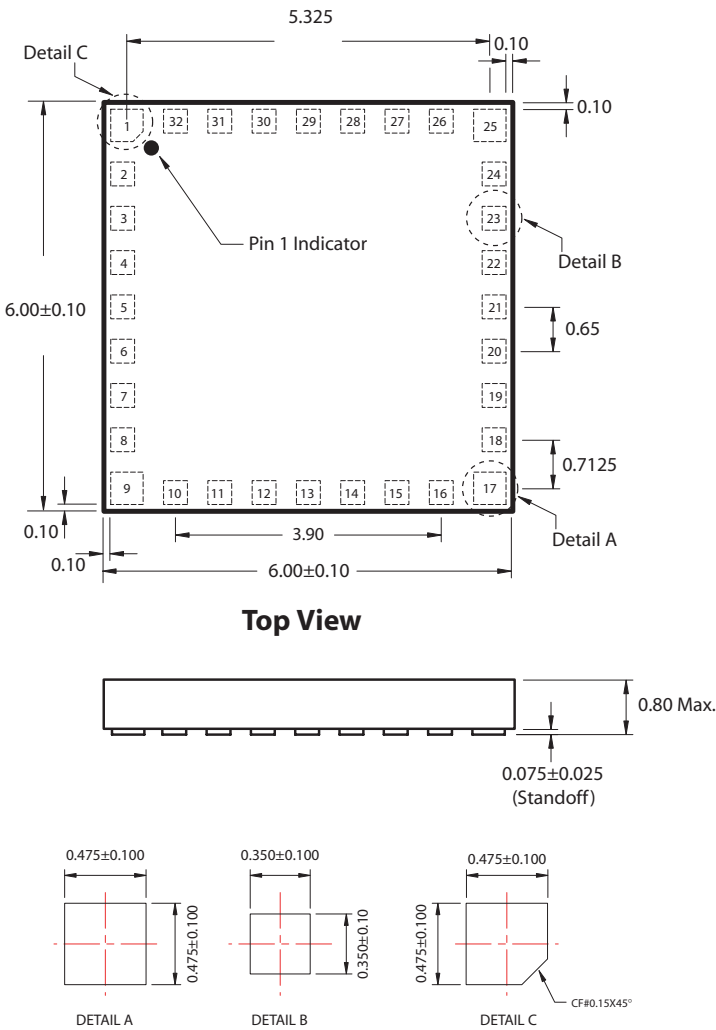
28-Lead PLCC Package Outline (PJ)



Pin Configuration

Pin #	Pin Name	Pin #	Pin Name
1	SW3	15	NC
2	SW3	16	D_{IN}
3	SW2	17	CLK
4	SW2	18	$\overline{LE}$
5	SW1	19	CLR
6	SW1	20	D_{OUT}
7	SW0	21	SW7
8	SW0	22	SW7
9	NC	23	SW6
10	V_{PP}	24	SW6
11	NC	25	SW5
12	V_{NN}	26	SW5
13	GND	27	SW4
14	V_{DD}	28	SW4

32-Lead BCC
Package Outline (B1)



Note: All dimensions are in mm and angles are in degrees

Pin Configuration

Pin #	Pin Name	Pin #	Pin Name
1	NC	17	NC
2	SW5	18	V _{NN}
3	SW5	19	NC
4	SW4	20	GND
5	SW4	21	V _{DD}
6	SW3	22	D _{IN}
7	SW3	23	CLK
8	SW2	24	$\overline{\text{LE}}$
9	SW2	25	CLR
10	NC	26	D _{OUT}
11	SW1	27	NC
12	SW1	28	SW7
13	SW0	29	SW7
14	SW0	30	SW6
15	NC	31	SW6
16	V _{PP}	32	NC

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information go to <http://www.supertex.com/packaging.html>.)

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